

# Bidirectional Ultra Low Capacitance TVS Array

#### **DESCRIPTION**

The TUSD03FBXSeries are ultra low capacitance transient voltage suppressor arrays, designed to protect applications such as portable electronics and SMART phones. This series is available in both unidirectional and bidirectional configurations and is rated at 350 Watts for an 8/20µs waveshape.

The TUSD03FBX and Series meets IEC 61000-4-2 (ESD) and IEC 61000-4-4 (EFT) requirements. At higher operating frequencies or faster edge rates, insertion loss and signal integrity are a major concern. This series offers a ultra low capacitance and low leakage current in a miniature SOD-323 package.

## **ORDERING INFORMATION**

Device: TUSD03FBXPackage: SOD-323Material: Halogen freePacking: Tape & Reel

♦ Quantity per reel: 3,000pcs

### **FEATURES**

- ♦ IEC61000-4-2 (ESD) ±15kV (air), ±8kV (contact)
- ♦ IEC61000-4-4 (EFT) 40A (5/50ns)
- ♦IEC61000-4-5 (Lightning) 12A (8/20μs)
- ♦ Protects one I/O line (bidirectional)
- ♦ Low clamping voltage
- ♦ Working voltages : 3V
- ♦ Low leakage current
- ♦ Response Time is < 1 ns</p>

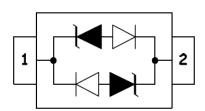
# **MACHANICAL DATA**

- ♦ SOD-323 package
- ♦ Flammability Rating: UL 94V-0
- ♦ Packaging: Tape and Reel
- ♦ High temperature soldering guaranted:260°C/10s
- ♦ Reel size: 7 inch

### **APPLICATIONS**

- ♦ Cell Phone Handsets and Accessories
- ♦ Microprocessor based equipment
- ♦ Personal Digital Assistants (PDA's)
- ♦ Notebooks, Desktops, and Servers
- ♦ Portable Instrumentation
- ♦ Peripherals
- ♦USB Interface

#### **PIN CONFIGURATION**



#### **PACKAGE OUTLINE**





ABSOLUTE MAXIMUM RATING							
Symbol	Parameter	Value	Units				
V <sub>ESD</sub>	ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	±15 ±8	kV				
P <sub>PP</sub>	Peak Pulse Power (8/20μs)	300	W				
T <sub>OPT</sub>	Operating Temperature	-55/+150	°C				
T <sub>STG</sub>	Storage Temperature	-55/+150	°C				
T∟	Lead Soldering Temperature	260	°C				

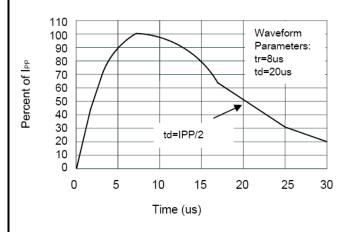
ELECTRICAL CHARACTERISTICS (Tamb=25°C)									
5.05	55,405	$V_{RWM}$	V <sub>B</sub>	I <sub>T</sub>	V <sub>C</sub> @1	V	С	I <sub>R</sub>	Ст
PART NUMBER	DEVICE MARKING	(V)	(V)	(mA)	(V)	(\	<b>'</b> )	(µA)	(pF)
NOMBER	W at the state of	(max.)	(min.)		(max.)	(max.)	(@A)	(max.	(typ.)
TUSD03FBX	3B	3.0	4.0	1	7.0	13.9	8	2	0.8

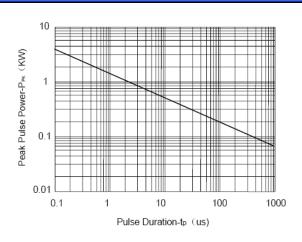
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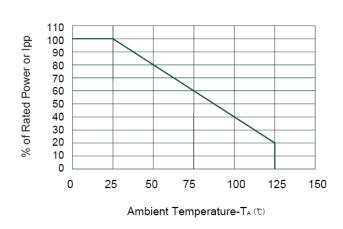
### **ELECTRICAL CHARACTERISTICS CURVE**

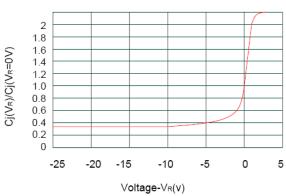




#### **Pulse Waveform**

Non-Repetitive Peak Pulse Power vs. Pulse Time



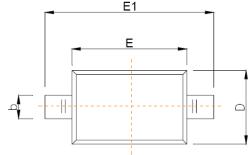


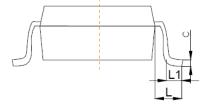
**Power Derating Curve** 

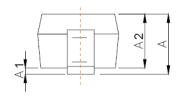
Junction Capacitance vs. Reverse Voltage



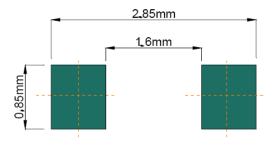








Cymbol	Dimensions In Millimeters				
Symbol	Min	Max			
Α		1.00			
A1	0.000	0.100			
A2	0.800	0.900			
b	0.250	0.350			
С	0.080	0.150			
D	1.200	1.400			
Е	1.600	1.800			
E1	2.500	2.700			
е	1.800	2.040			
L	0.475 REF				
L1	0.250	0.400			
θ	0°	8°			



**Recommended Pad outline**